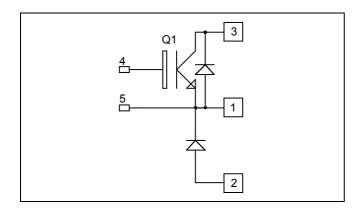
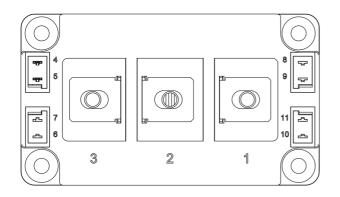


Buck Chopper Trench + Field Stop IGBT3 Power Module





# APTGT400SK60D3G

## $V_{CES} = 600V$ $I_C = 400A$ @ Tc = 80°C

#### Application

- AC and DC motor control
- Switched Mode Power Supplies

#### Features

- Trench + Field Stop IGBT3 Technology
  - Low voltage drop
  - Low tail current
  - Switching frequency up to 20 kHz
  - Soft recovery parallel diodes
  - Low diode VF
  - Low leakage current
  - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- High level of integration
- M6 power connectors

#### Benefits

- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive T<sub>C</sub> of V<sub>CEsat</sub>
- RoHS Compliant

### Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V <sub>CES</sub>	Collector - Emitter Breakdown Voltage		600	V
I <sub>C</sub>	Continuous Collector Current	$T_C = 25^{\circ}C$	500	
1 <sub>C</sub>	Continuous Conector Current	$T_C = 80^{\circ}C$	400	Α
I <sub>CM</sub>	Pulsed Collector Current	$T_C = 25^{\circ}C$	800	
$V_{GE}$	Gate – Emitter Voltage		±20	V
P <sub>D</sub>	Maximum Power Dissipation	$T_C = 25^{\circ}C$	1250	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 125^{\circ}C$	800A @ 520V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com APTGT400SK60D3G - Rev 2 October, 2012



- 4

## All ratings (a) $T_j = 25^{\circ}C$ unless otherwise specified

Electrical Characteristics								
Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit	
I <sub>CES</sub>	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 600V$				500	μA	
V <sub>CE(sat)</sub>	Collector Emitter saturation Voltage	$V_{GE} = 15V$	$T_j = 25^{\circ}C$		1.5	1.9	V	
V CE(sat)	Conector Emitter saturation voltage	$I_{\rm C} = 400 {\rm A}$ $T_{\rm j} = 150^{\circ} {\rm C}$		1.7		v		
V <sub>GE(th)</sub>	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 6.4 \text{ mA}$		5.0	5.8	6.5	V	
I <sub>GES</sub>	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				400	nA	

### **Dynamic Characteristics**

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$		24		
Coes	Output Capacitance	$V_{CE} = 25V$		1.5		nF
C <sub>res</sub>	Reverse Transfer Capacitance	f = 1 MHz		0.75		
Q <sub>G</sub>	Gate charge	V <sub>GE</sub> =±15V, I <sub>C</sub> =400A V <sub>CE</sub> =300V		4.2		μC
T <sub>d(on)</sub>	Turn-on Delay Time	Inductive Switching (25°C)		110		
Tr	Rise Time	$V_{GE} = \pm 15V$		50		
T <sub>d(off)</sub>	Turn-off Delay Time	$V_{Bus} = 300V$ $I_{C} = 400A$		490		ns
$T_{\rm f}$	Fall Time	$R_G = 1.5\Omega$		50		
T <sub>d(on)</sub>	Turn-on Delay Time	Inductive Switching (150°C)		130		
$T_{\rm r}$	Rise Time	$V_{GE} = \pm 15V$ $V_{Bus} = 300V$		60		ns
T <sub>d(off)</sub>	Turn-off Delay Time	$I_{\rm C} = 400 \text{A}$		530		115
$T_{\rm f}$	Fall Time	$R_G = 1.5\Omega$		70		
Eon	Turn on Energy	$V_{GE} = \pm 15V$ $T_j = 25^{\circ}C$		3.2		
Lon	Turn on Energy	$V_{Bus} = 300V$ $T_i = 150^{\circ}C$		3.4		mJ
E <sub>off</sub>	Turn off Energy	$I_C = 400A$ $T_j = 25^{\circ}C$		15		1110
2011	- and on Enoigy	$R_G = 1.5\Omega$ $T_i = 150^{\circ}C$		15.5		
I <sub>sc</sub>	Short Circuit data	$V_{GE} \le 15V$ ; $V_{Bus} = 360V$ $t_p \le 6\mu s$ ; $T_j = 150^{\circ}C$		2000		А

### **Reverse diode ratings and characteristics**

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V <sub>RRM</sub>	Maximum Peak Repetitive Reverse Voltage			600			V
I <sub>RRM</sub>	Maximum Reverse Leakage Current	V <sub>R</sub> =600V	$T_i = 25^{\circ}C$ $T_i = 150^{\circ}C$			500 750	μΑ
I <sub>F</sub>	DC Forward Current		$Tc = 80^{\circ}C$		400		А
V <sub>F</sub>	Diode Forward Voltage	$I_{\rm F} = 400 {\rm A}$ $V_{\rm GE} = 0 {\rm V}$	$T_i = 25^{\circ}C$ $T_i = 150^{\circ}C$		1.6 1.5	2	V
t <sub>rr</sub>	Reverse Recovery Time	$I_{F} = 400A V_{R} = 300V di/dt = 4800A/\mu s$	$T_j = 25^{\circ}C$ $T_i = 150^{\circ}C$		125 180		ns
Q <sub>rr</sub>	Reverse Recovery Charge		$T_j = 25^{\circ}C$ $T_i = 150^{\circ}C$		18.8 39.5		μC
Err	Reverse Recovery Energy		$T_{j} = 25^{\circ}C$ $T_{j} = 150^{\circ}C$		4.4 9.6		mJ

2 - 6

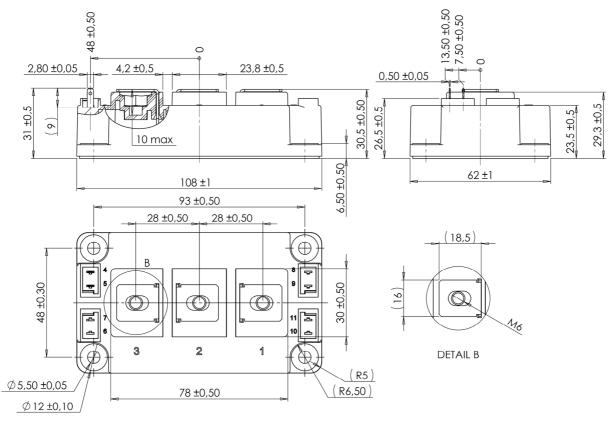


# APTGT400SK60D3G

### Thermal and package characteristics

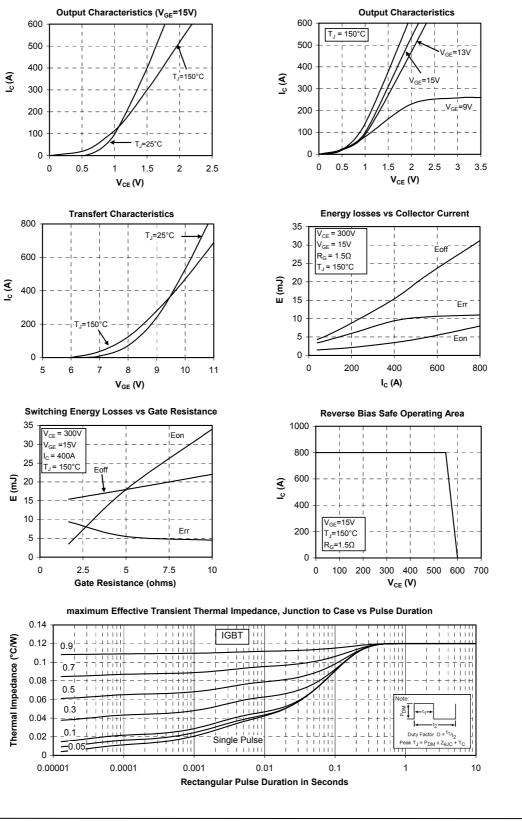
Symbol	Characteristic			Min	Тур	Max	Unit	
R <sub>thJC</sub>	Junction to Case Thermal Resistance		IGBT			0.12	°C/W	
<b>R</b> <sub>th</sub> JC			Diode			0.20		
V <sub>ISOL</sub>	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V	
T <sub>J</sub>	Operating junction temperature range			-40		175		
T <sub>STG</sub>	Storage Temperature Range			-40		125	°C	
T <sub>C</sub>	Operating Case Temperature			-40		125		
Torque	Mounting torque	For terminals	M6	3		5	N.m	
		To Heatsink	M6	3		5	19.111	
Wt	Package Weight					350	g	

### D3 Package outline (dimensions in mm)





### **Typical Performance Curve**



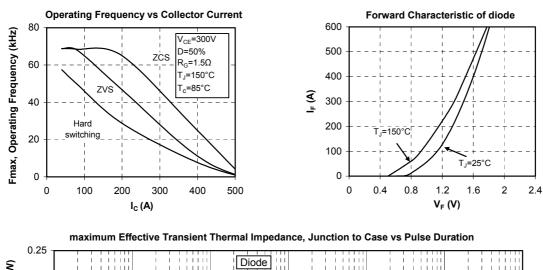
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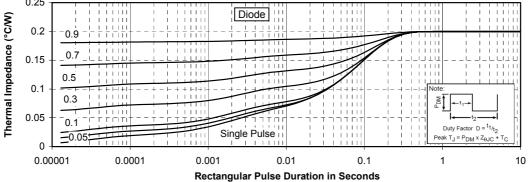
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